



L	Hits	Search Text	DB	Time stamp
Number				
1	54119	semiconductor and cmos	USPAT;	2003/07/11
			US-PGPUB;	13:38
			EPO; JPO;	İ
			DERWENT;	
			IBM TDB	
2	1099	(semiconductor and cmos) and (work adj	USPAT;	2003/07/11
		function)	US-PGPUB;	13:39
		·	EPO; JPO;	
			DERWENT;	
1			IBM TDB	1
3	792	((semiconductor and cmos) and (work adj	USPAT;	2003/07/11
1		function)) and (gate adj electrode)	US-PGPUB;	13:39
			EPO; JPO;	
			DERWENT;	1
			IBM TDB	1
4	217	(((semiconductor and cmos) and (work	USPAT;	2003/07/11
		adj function)) and (gate adj	US-PGPUB;	13:40
		electrode)) and (titanium adj nitride)	EPO; JPO;	
		and titanium	DERWENT;	
			IBM_TDB	